



DEVETECH ELECTRONICS CO. LTD

**LED LAMP (Ø3 YG)
CUSTOMER: DACHS ELECTRONICA
P/N: DVL311MG**

DESIGNED BY	
CHECKED BY	
APPROVED BY	

Address: 11/F.,F.Block, Hang Lok Building, 130Wing Lok St., Hong Kong.

Address: A3L1, Youpinyishu, Huanmei Rd., Dameisha, Yantian district, Shenzhen, China

Tel: (86) 13632770721 Email: sales@devetechelectronics.com Website: www.devetechelectronics.com



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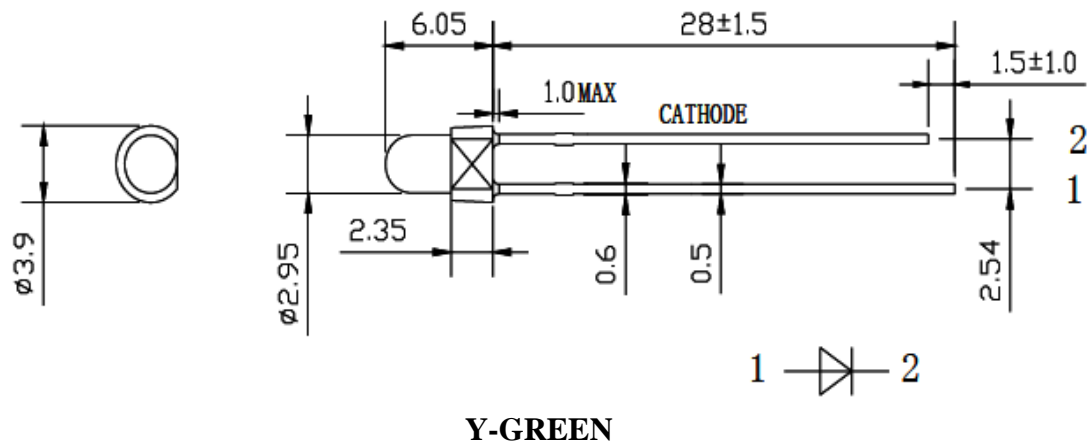


Change N°	Date	Subject and reason	Version N°	Responser
1	2014.08.07		A0	

1. FEATURES

- * Ø3 DIAMETER LAMP
- * LOW CURRENT REQUIREMENT
- * LOW POWER CONSUMPTION
- * VERSATILE MOUNTING ON P.C. BOARD PANEL
- * LONG LIFE-SOLID STATE RELIABILITY

2. PACKAGE DIMENSIONS



Notes:

1. All dimensions are in millimeters.
2. Tolerance is ± 0.25 mm, unless otherwise noted.



3. CENTRAL INFORMATION

Part No.	Chip material	Emitting color	Lens type	Iv (mcd) 20mA			Viewing angle
				Min.	Typ.	Max.	2 θ 1/2
DVL311MG	AlGaInP	Y-GREEN	Green Diffused	10	30	-	60°

Note:

θ 1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

4. ELECTRICAL / OPTICAL CHARACTERISTICS AT T_A=25°C

Parameter	Symbol	Min.	Typ.	Max.	Units	Test conditions
Forward voltage	V _F	1.8	2.1	2.4	V	I _F =20mA
Peak wavelength	λ_p	-	-	-	nm	I _F =20mA
Dominate Wavelength	λ_D	568	571	576	nm	I _F =20mA
Spectral line half-width	$\Delta \lambda$	-	20	-	nm	I _F =20mA
Reverse current	I _R	-	0	10	uA	V _R =5V

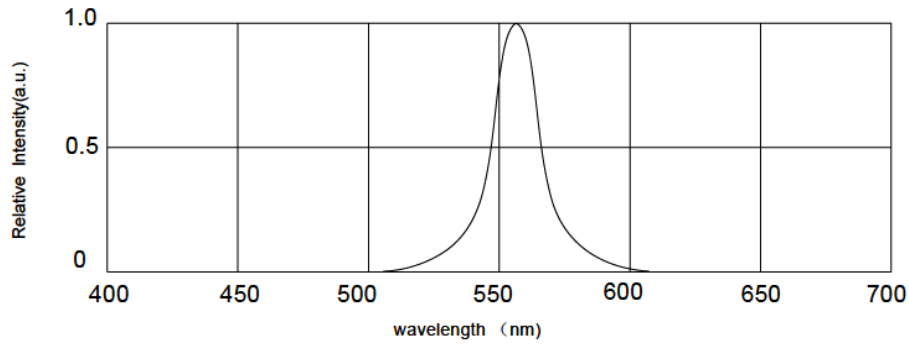
5. ABSOLUTE MAXIMUM RATINGS AT T_A=25°C

Parameter	Symbol	Maximum ratings	Units
Power dissipation	P _d	70	mW
Forward current	I _F	25	mA
Peak forward current	I _F (Peak)	130	mA
Reverse voltage	V _R	5	V
Operating temperature	T _{opr}	-40°C to +85°C	
Storage temperature	T _{stg}	-40°C to +100°C	
Solder temperature	T _{sol}	260°C for 3 seconds	

Note:

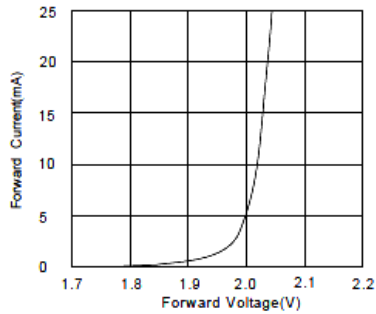
1. 1/10 duty cycle, 0.1ms pulse width.
2. 3mm below package base.
3. The production accord with the demand of RoHS.

6. RELATIVE INTENSITY VS WAVELENGTH CHART

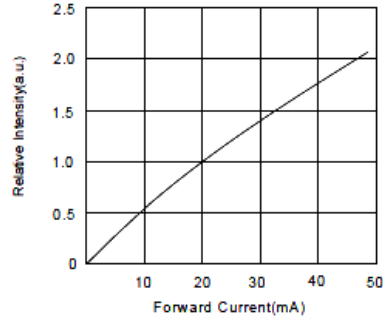


RELATIVE INTENSITY Vs. WAVELENGTH

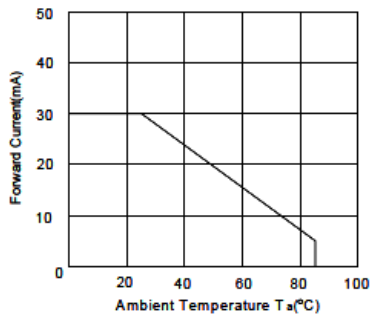
7. TYPICAL ELECTRO-OPTICAL CHARACTERISTICS CURVES



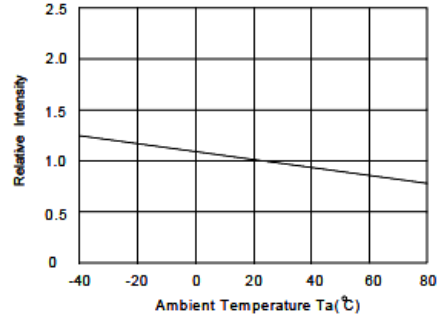
FORWARD CURRENT Vs. FORWARD VOLTAGE



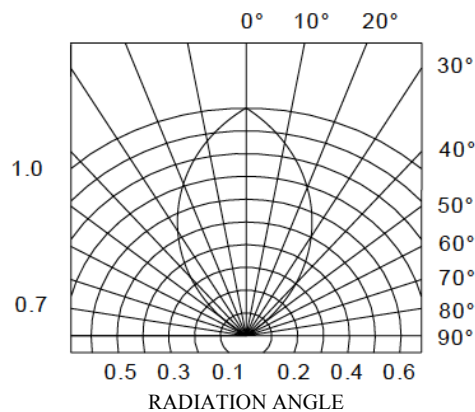
LUMINOUS INTENSITY Vs. FORWARD CURRENT



FORWARD CURRENT DERATING CURVE



RELATIVE INTENSITY Vs. AMBIENT TEMPERATURE



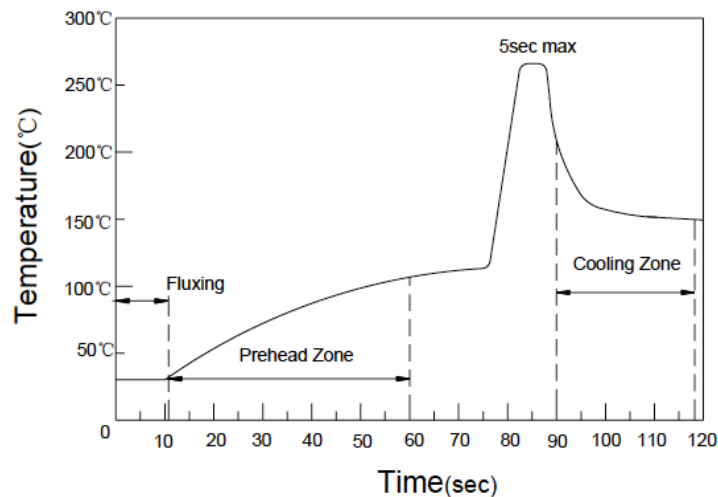
8. RELIABILITY

8.1. Test items and results

Test items	Test conditions	Sample quantity	Test results
Solder ability	Solder temperature: (235±5°C) Solder duration: 5sec.	35	Good wetting
Resistance for soldering heat	(260±5°C) 10sec.	35	OK
Thermal shock	-40°C ~ 25°C ~ 100°C ~ 25°C 30min 5min 30min 5min	35	OK
High temperature and high humidity	Ta=85°C RH=85%	35	OK
High temperature storage	Ta=100°C	35	OK
Low temperature storage	Ta=-40°C	35	OK
Life test	Ta=20°C I _F =20mA	35	OK

8.2. Soldering instructions

1. Recommended soldering profile:



2. Dip and hand soldering should not be done more than one time.
3. Please note that stress to the leads and epoxy bulb should be avoided during soldering particularly when heated. After soldering the LED's should be protected from mechanical shock or stress before the LED's cool down to room temperature.
4. Cut the lead frames after the LED's return to room temperature.



NOTES
